## TECHNOLOGIES FOR MICROFABRICATION OF MEMS DEVICES

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A WEMS process has the goal of creating superioled microstructures, accessible Through electrical signals. To This purpose, it is fundamental to create conductive and superioled points interconnections (electrodus) and shall paps useful for the capacitive sensing on which mostly inertial sensors are based. Finally operation in vaccum anables damping and Thus noise win mixation

1. structural layer prouth (Epitamial growth)
2. smoothral layer etaking (DRIE)
3. release of the polytilican frames The online process is divided into 4 steps:

4. packaging

1. The first steps, confishing in the STRUCTURAL LAYER GROWTH, is usually performed Through a procedure known is Epitaxian Growth where a thick layer of polysilican is formed by mixing a proper quantity of precured posses in a chamber, properly heated and kept at a proper pressure.

The one of thickness of the obtained layer, usually ranging in the 20-70 pm range is fundamental for inertial sensors, as Their intrinsic naise (NETTO and NERD), indeed, decreases we increasing man values and so we increasing thickness.

Another relevant object is The Thickness uniformity but it offects the resonance frequency of out-of-plane (ODP) mades, generating different sensitivity from part to part in t-owns acceleronaters, due to The various intry of the resonance frequency, or different sensitivity from post to part of pitch/roll pyroscopes, due to the variability of hade-shit values, for introdu

2. The second step in the microfolication is the STRUCTURAL LAYER ETCHING which is used to define The stope of The suspended points. It is fundamental to reach a high form-factor, so to have harrow and deep trenders. For This reason, isotropic etaling is not a pood opinion but it's better to use an ANDOTROPIC ETCHING APPROPRIM which is obtained Through a procedure town as bett reperive 1000 etching (DRIE) where a high form-factor (N30) can be abtained Through The conscarrive apprication of small isotropic etching w) following protection of sidewalls (of The and of each eveps) which determines a guar-vartical etching at The and

To pool is to etch as small gops as possible, as This sets the transduction factor of copacitive driving and sensing. W lawer paps, we can obtain the same nation coing lower driving sphals, or larger signals for the same nation can be advised. In thin, This is beneficial to reduce input referred effects of electronic naise

Once apoin, The pops uniformity to fundamental. Differences in etaling, from part to part, may induce differences in resonance frequency (due to spring extring) or in transduction factor (due to per etaling).

Additionally local differences on the some smoother may induce quadrature errors in pyrocopes From this standarist, elso The sidemans of the formality (so could STEN ANOW FRECT) is fundamental to avoid OOP effects of drive forces in pitch roll synoscopes.

· Isotropic - in The all directions w The some internsity

- onisotropic → especially in one desired direction
- 3 Once the structural layer shape is defined, it's The turn of POLYSICION FRANTS PENSASE. This is obtained by etaling the sacrificial oxide underneath the smoother through proper pases. This etching advances by a distance, underneath the structure, which is proportional to the many ways tent creek and to their munimin but ack centre out 4978 ent : with grantes . 27:09 belonger ant to Albin numinar art as 0310 21 wind beneather Wherever a suspended frame should be larger than this width haves in the frame should be positioned to to often the conect where

4. Finally, PACKAGING IS used for a triple role of: a protective the structure from external dust; b tething The proper operation pressure so adopting the Q factor to the specification requirements C forming on inert pos environment to avoid silicon exidation during the device lifetime The 17th consists in BONDANG a CAP water on The top of The HEMS water, where bounding is ensured by a proper material realing the WEMS county.

In generate, There exist 2 banding techniques, according to the type of material used to real The MEMS covity · GLASS-FRIT BONDING: uses a sort of glass pander called plax-frit, which welts at reasonably law temperatures, compared to netal nelting temperatures · FUTECTIC BONDING: uses on allow of material that under thermo-compression metts to form the sealing Once more, repeatability of the package pressure from part to part is fundamental to ensure performance repeatability of different structures: indeed pressure influences the O factor and in turn out the parameters that are a function of it (noise, ringular time, boundwidth, motion amphode...)